

Today's Agenda

- About Micron Technology
- Memory Market Overview
 - Memory Transition
- Storage Market Overview
- What's new in the SSD Technology
 - Micron 5210 SSD drive
- SSD Product Range





NAND Flash Manufacturers DRAM Manufacturers

3D XPoint™ Manufacturers



NAND, DRAM, & 3D XPoint™ Manufacturer











26,000 Lifetime Patents

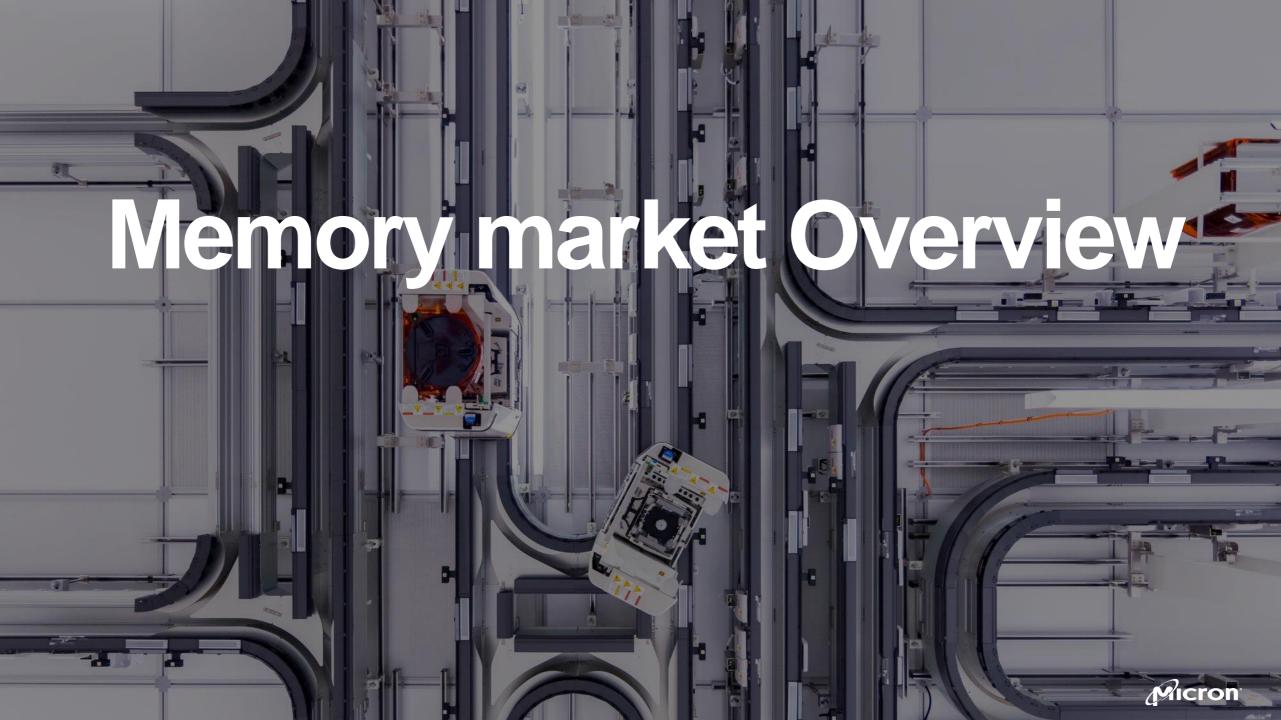
(One every day for the past 72 years)











Worldwide Memory \$128 BMarket (+59% Y/Y)



Semiconductor Market in 2017 \$403B

DRAM

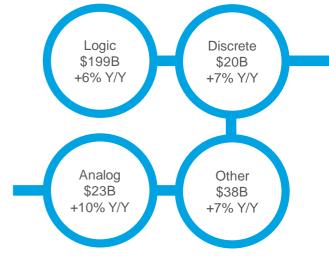
- Mobile \$24B
- Non-Mobile \$45B

\$69B (+65% Y/Y)

Non-Volatile

- Storage \$25B
- Non-Storage \$34B

\$59B (+52% Y/Y) Non-Memory Markets \$275B



Source: Gartner Q2-16 and Micron

¹Memory includes DRAM, NAND and NOR, Emerging and other



Trends Impacting the DRAM Market

Content



Demand Strong



2017 Supply Growth

2017 Content Trends

Server 32GB DDR4 RDIMM mainstream with 64GB ramp starting

iPhone moves to majority 3GB

Android flagship phones move from 3GB to 4GB (Spring) and 6GB (Autumn) in 2017

<u>Demand Growth</u>

Cloud: 59%

Enterprise: 25%

Networking: 38%

Mobile 23%

Graphics: 16%

Client: 5%

2017 Overall

Limited wafer growth

Transition to 8Gb mono die largely complete

Fewer LP and DD bits per wafer relative to DDR3

> 2017 Overall Bit Growth at 22%

Usage trends

updated 8/17/17

Bit Growth at 24%

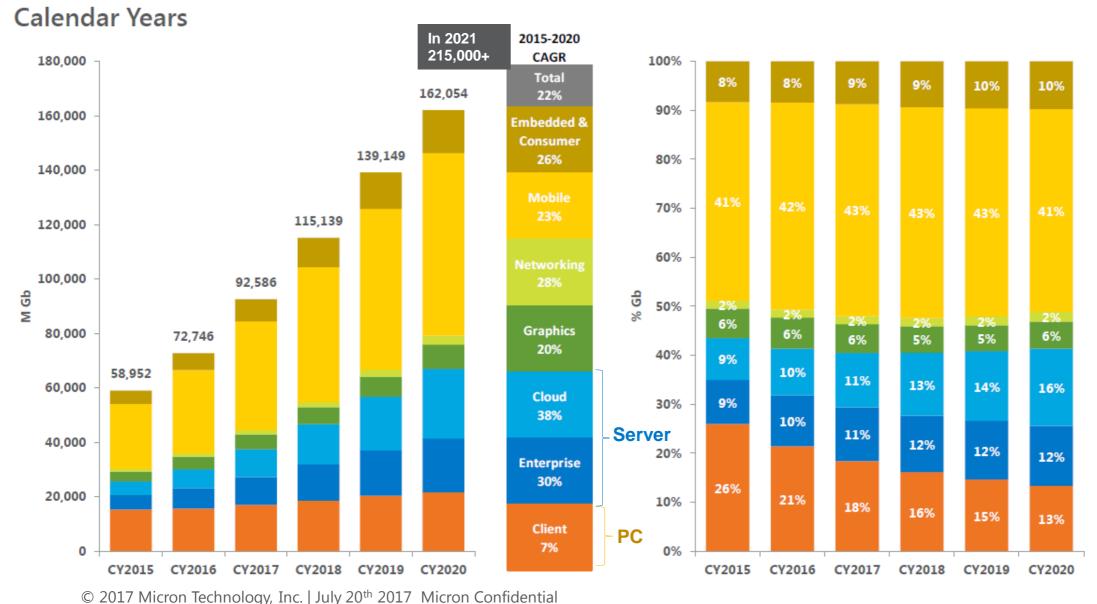


Micron Confidential

Sources: Micron CQ3'17, Industry analysts, DRAMeXchange

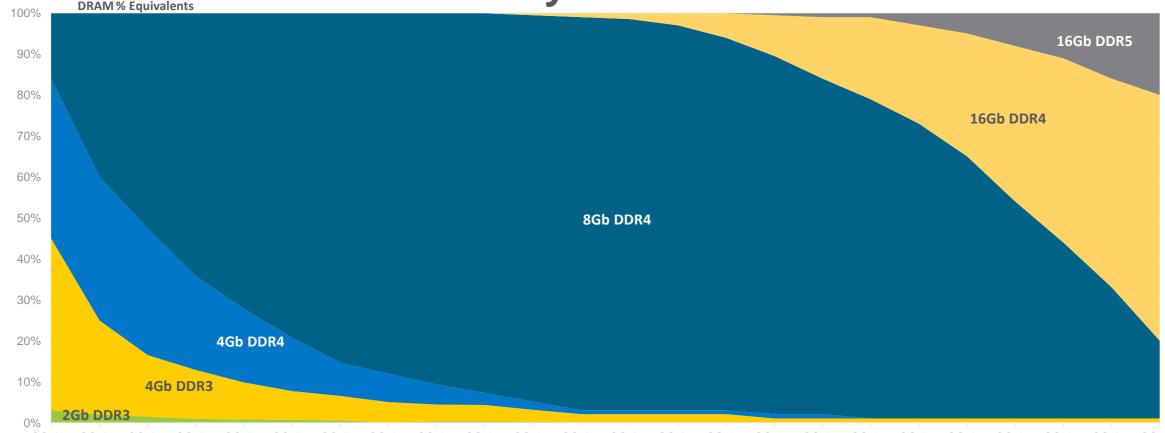


DRAM Market by Segment





Server DRAM Market Density Transitions



CQ1'	16 CQ2'16 CQ3'16 CQ4'16	CQ1'17 CQ2'17 CQ3'17 CQ4'17	CQ1'18 CQ2'18 CQ3'18 CQ4'18	CQ1'19 CQ2'19 CQ3'19 CQ4'19	CQ1'20 CQ2'20 CQ3'20 CQ4'20	CQ1'21 CQ2'21 CQ3'21 CQ4'2
Mainstream	<u>2016</u>	<u>2017</u>	<u>2018</u>	<u>2019</u>	<u>2020</u>	<u>2021</u>
Speed (MTs) / Voltage	2400 1.2V	2400/2666 1.2V	2666/2933 1.2V	2933/3200 1.2V	3200/4000 1.2/1.1V	4000/4400 1.1V
Tech	DDR4	DDR4	DDR4	DDR4	DDR4/DDR5	DDR5

Source: Micron Business Development - 3Q17





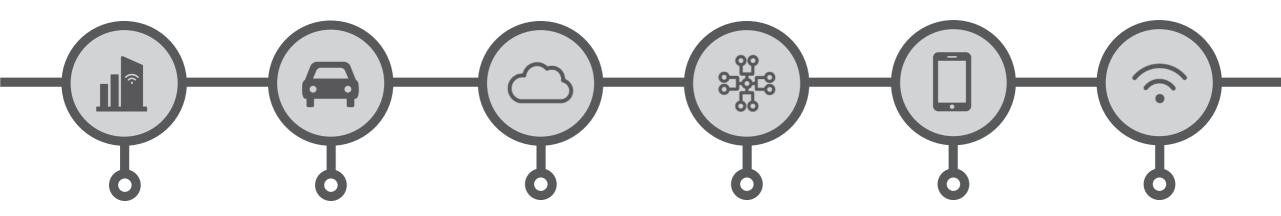
163 trillion gigabytes)

(by) 2025

163,000,000,000,000GB !! - That's 10X more than all the data generated in 2016



Trends Driving Increased Data Traffic



Enterprise

OLTP systems with low-latency in-memory compute

Automotive

Customer-ready autonomous vehicles by 2021

Cloud/ Big Data

44 zettabytes of data stored annually

Networking

Global IP traffic grows at a CAGR of 24% from 2016 to 2020

Mobile/ Client

Global mobile data traffic to rise ~7X between 2016 and 2021

IoT

20 billion connected devices by 2020

Source, September 2017: Cisco, Gartner, IDC, Automobile manufacturers $IoT-Internet\ of\ Things$



Top 3 Storage Trends

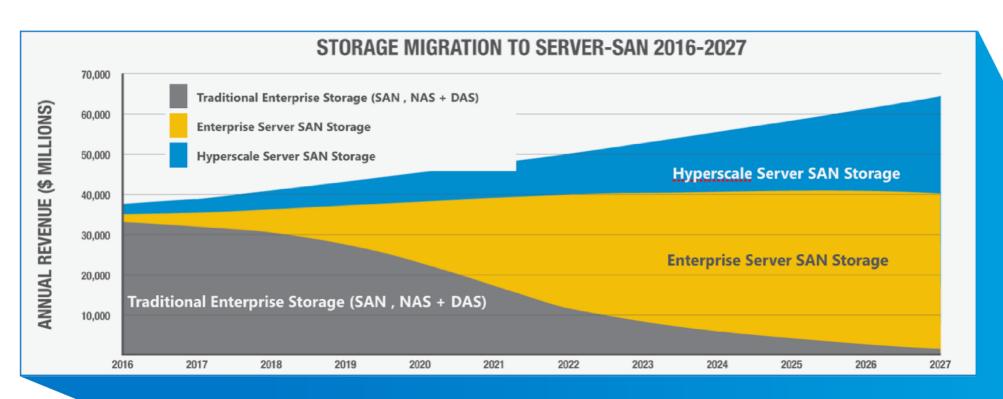
- 1 In 2016, flash represented 10% of all storage gigabytes shipped
- Workloads have become more random/real-time
- Continued drive to bring data closer to compute



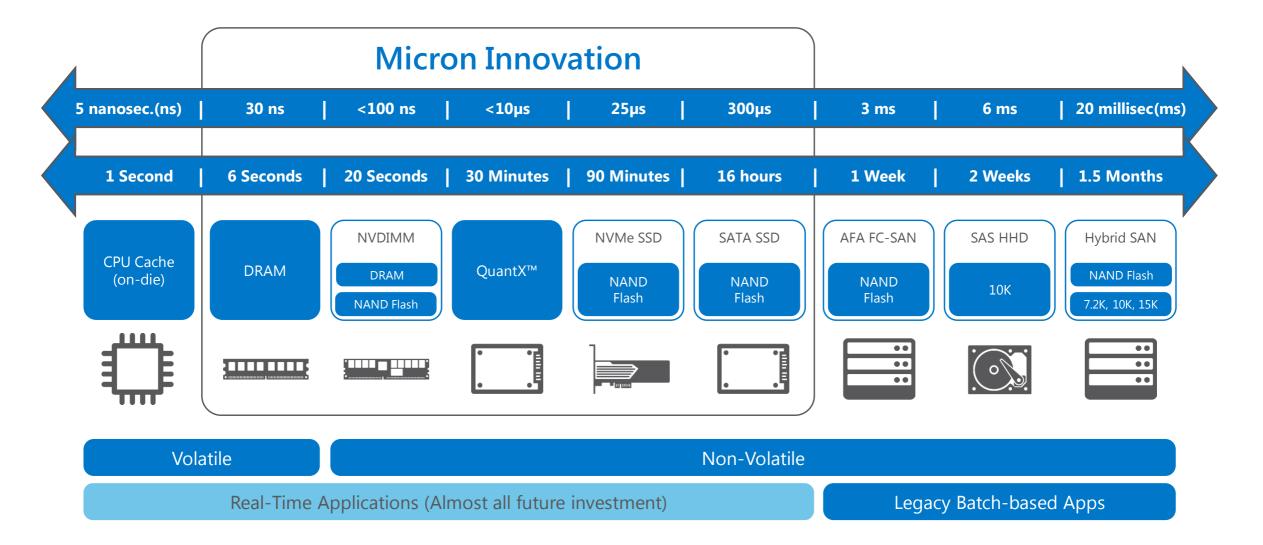




Massive storage migration to server-SAN



Applications Increasingly Rely on Fast Storage



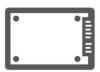


NVMe Market Highlights



NVMe Market Size

The NVMe market will reach \$60B by 2021



NVMe SSD U.2 & M.2 in Servers

Over 50% of enterprise servers will be NVMe-enabled by 2019



SSD Storage Applications

Over 70% of appliances will be NVMe-enabled by 2021



NVMe-oF Networking

NVMe-oF adapter shipments will exceed 1.5M units by 2021



AFA Moves to NVMe

Over 70% of AFAs will be NVMe-based by 2020



NVMe SSD Market Growth

The market for NVMe SSDs (U.2, M.2, and PCle AOCs) will reach \$9B by 2021



What's lew: vSAN NVMe & SATA RA

"Micron All-Flash NVMe and SATA **vSAN 6.6 RA**"

ron Reference Architecture

Easy to integrate vSAN platform that's price/perf. balanced

Reference Architecture

Micron® Accelerated All-Flash NVMe™ and SATA vSAN™ 6.6 Solution

Reference Architecture













Modernizing the Data Center: What Does This Mean?

The New ROI: Return on Infrastructure



Lower Power Consumptio n



End-to -End
Data
Protection
and Security



Reduced Maintenance Costs



Greater Operating Efficiency





Select the level of security you need

PURPOSE-APPROPRIATE DATA PROTECTION AND SECURITY



Secure Download & Diagnostics

- Firmware feature
- Protects the drive from software attacks through a digital signature built into the firmware
 - When downloads are needed, the digital signature prevents unauthorized access to the drive
 - Prevents counterfeit firmware from being loaded to the drive





TCG-Enterprise Encryption

- Data security standard
- Enterprise focused
- Trusted Computing Group
- Protects Data-at-Rest through encryption
 - Encryption key generated by the SSD can never leave the drive
 - Strong Authentication can be used to "marry" the drive to ONE host
 - SSD, data can't be read without authentication key





FIPS 140-2 Validated

- Federal Information Processing Standard (FIPS) Publication 140-2
 - US Government security standard used to accredit cryptographic modules
 - Certifies that the module (Drive) meets a minimum standard for security and tamper resistance
 - Military grade encryption required by federal agencies



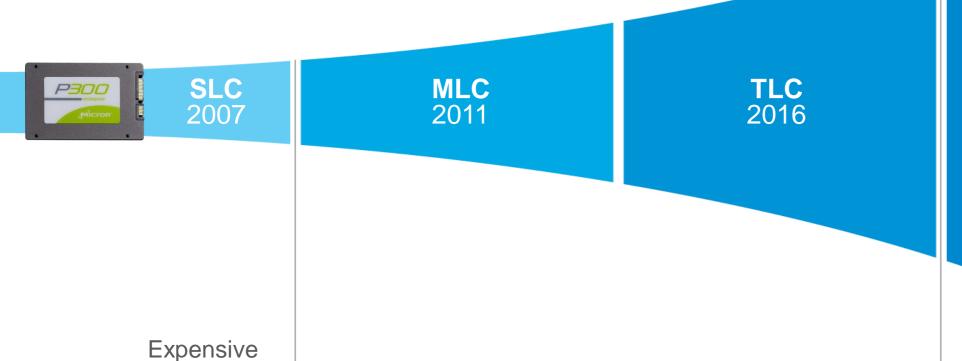






The Evolution of Enterprise SSDs

Business priorities drive workloads. Workloads drive storage, performance, and capacity.



QLC 2018



Affordable High Capacity



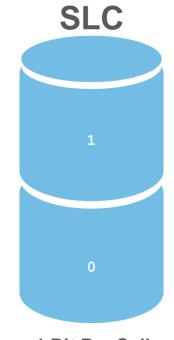
Low Capacity



QLC = More Density Per NAND Cell

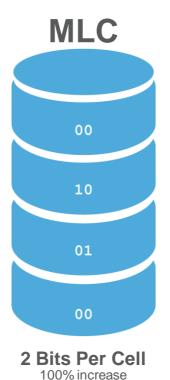


Lower \$ per GB

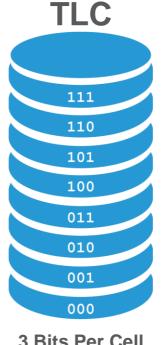


1 Bit Per Cell First SSD NAND technology

100K P/E Cycles (at technology introduction)

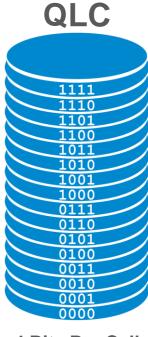


10K P/E Cycles



3 Bits Per Cell 50% increase

3K P/E Cycles



4 Bits Per Cell 30% increase

1K P/E Cycles



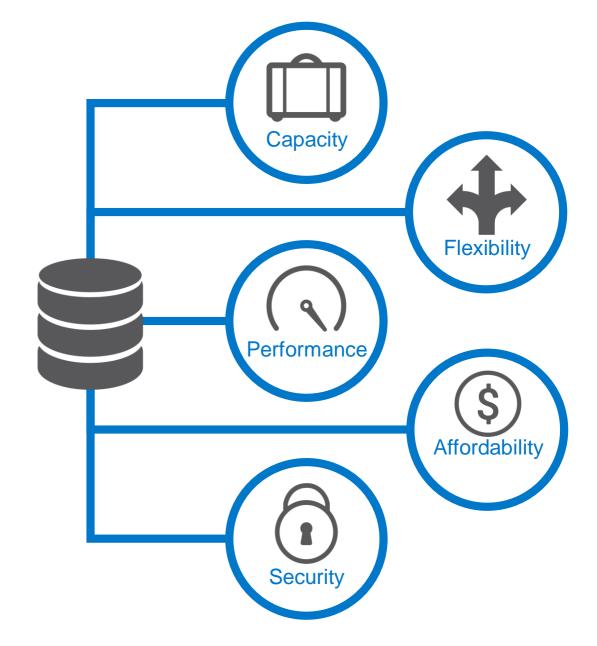
Fewer writes per cell



The QLC Workload Advantage

Right-Sized, Cost-Effective Performance for Read-Intensive Workloads

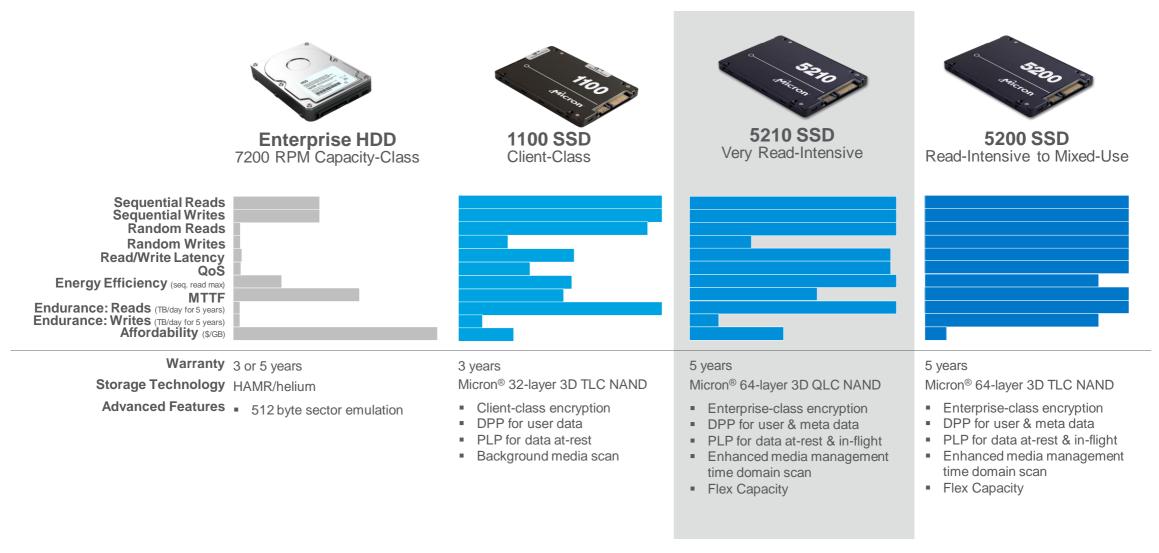
- Big Data analytics & read-centric data stores
 - BI/DSS: MySQL, Oracle, MS SQL
 - Big Data: Hadoop HDFS
 - Deep Learning
 - Ceph: Active archive/block store
 - NoSQL: Mongo DB, Cassandra (photo tags, profile caches)
- VoD, content delivery, media streaming
- VM/data center backup & restore
- User authentication





SATA Possibilities for Enterprise Applications

Longer bar = better. All approximations are for steady-state performance and vary by capacity.

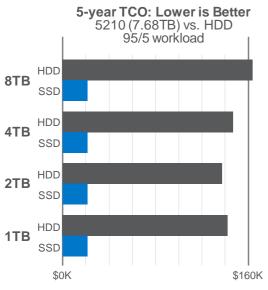




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Micron 5210 vs. 7200 RPM Hard Drive



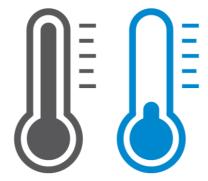


more capacity per 2U chassis

246TB VS. 128TB

3**X**

less power for sequential reads (max)



50%

reduction in server footprints

Racks needed to store 50PB:



19 with HDDs

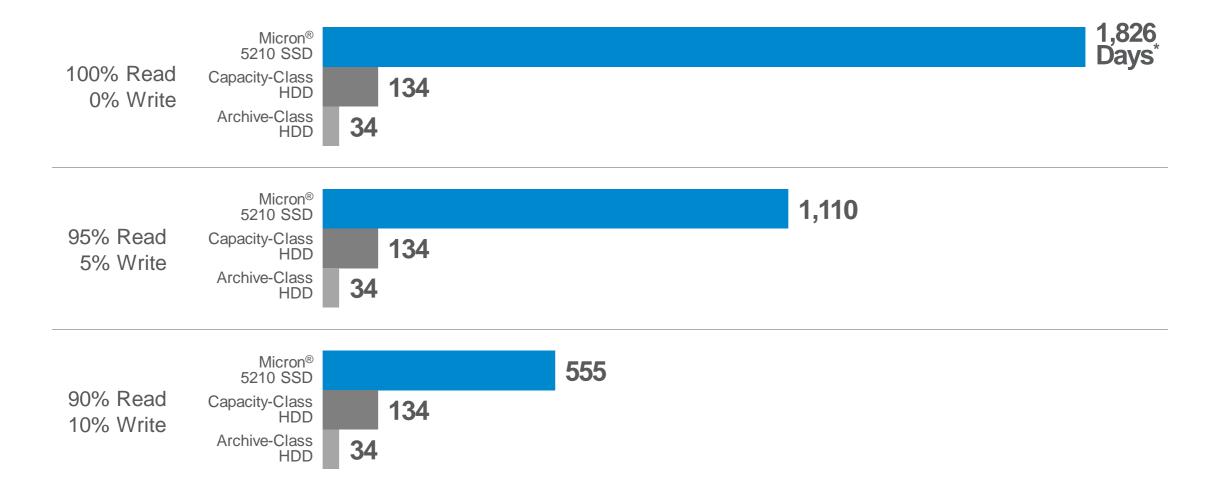




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8x More TBW With the 5210

Days it takes to exhaust an 8TB drive's endurance or warranty when running 24/7





SSD Product range

Storage Business Unit

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Micron® SSDs Deliver Data at the Speed of Now





Capture more value from more data. Faster.

Consumer Client Cloud/Enterprise May 11, 2018



Transitioning to the Micron 5200 is fast, easy & smart



Same controller
Same firmware
Same interface
Same features
Same components
New NAND

Easy quals. Better performance. Better value.



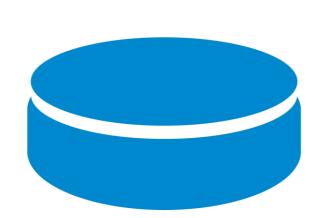
Same architecture & features as the proven 5100 SSD

Same drive. New NAND.

	5100	5200
SATA 6 Gb/s interface	~	~
2.5-inch (7mm) form factor	*	*
Marvell Dean controller	*	*
Micron custom firmware	*	*
Up to 7.68TB capacity	*	*
3 million hours MTTF	*	*
Encryption: AES 256-bit with TCG Enterprise configurability	~	~
5-year warranty	*	•
Micron® Flex Capacity	*	•
Power loss protection & data path protection	~	~
Adaptive thermal monitoring	*	•
TAA compliant	*	*
RAIN	*	*
Micron® 3D 64-layer TLC NAND	X	•



Better SSDs come from better NAND



Micron 5100
First generation
32-layer 3D NAND



Micron 5200 Second generation 64-layer 3D NAND



Only enterprise SATA SSD available in 64-layer 3D NAND*

- 512Gb TLC, 4 planes, 64kB parallelism
- Floating Gate + CMOS

Same cells. Smaller die. Taller skyscrapers. Better value.



How the 5200 Compares to the 5100

ECO

Better nearly across the board

and on latest NAND

	480GB ECO		960GB ECO		1920GB ECO		3840GB ECO		7680GB ECO	
	5100	5200	5100	5200	5100	5200	5100	5200	5100	5200
Seq Read (MB/s)	540	540	540	540	540	540	540	540	540	540
Seq Write (MB/s)	380	385	520	520	520	520	520	520	520	520
Random Read (IOPS)	93K	81K	93K	95K	93K	95K	93K	95K	93K	95K
Random Write (IOPS)	31K	33K	28K	28K	24K	22K	18K	17K	9k	10K
Endurance (TBW in PB)	0.45	0.87	0.9	1.75	3.2	3.5	6.4	7.7	8.4	8.4

1920GB PRO

960GR PRO

PRO

Lower random writes and endurance, but still best-in-class and on new NAND

	4000B11K0		30001		13200B1110		
	5100	5200	5100	5200	5100	5200	
Seq Read (MB/s)	540	_	540	540	540	540	
Seq Write (MB/s)	410	_	520	520	520	520	
Random Read (IOPS)	93K	_	93K	95K	93K	95K	
Random Write (IOPS)	43K	_	37K	32K	38K	32K	
Endurance (TBW in PB)	1.3	_	4.4	2.27	8.8	5.95	

480GR PRO

Capacity sweet spot



A Closer Look at the Micron® 5200 Series of SATA 2.5-inch SSDs

Model & Endurance Class	Read-Ir	PRO ntensive WPD								
Capacity	960GB*	1.92TB*	480GB	960GB	1.92TB	3.84TB	7.68TB			
Sequential Reads (MB/s) ¹	540	540	540	540	540	540	540			
Sequential Writes (MB/s) ¹	520	520	385	520	520	520	520			
Random Reads (K IOPS) ²	95	95	81	95	95	95	95			
Random Writes (K IOPS) ²	32	32	33	28	22	17	9.5			
Endurance (TBW in PB)	2.27	5.95	0.87	1.75	3.5	7.7	8.4			
NAND		Micron® 3D 64-layer TLC NAND								
Interface		SATA 6 Gb/s								
Form Factor	2.5-inch, 7mm									
MTTF	3 million device hours									
Advanced Features	Micron® Flex Capacity, AES 256-bit encryption, TCG Enterprise configurability, power loss protection for data in-flight, end-to-end enterprise data path protection, secure firmware, adaptive thermal monitoring, easy to install (hot pluggable), Storage Executive SSD management tool, RAIN, 5 year warranty, TAA compliant									

^{*}The Micron 5100 PRO will still be available in 240GB and 3.84TB capacities to support the widest range of configurations; 1. Sequential read/write @128KB (steady state); 2. Random read/write @ 4KB (steady state)



Target Workloads & Applications

The ideal SATA SSD for read-intensive, virtualized workloads that are crippled on a hard drive.

5200 ECO





Cloud Storage



Media Streaming

5200 PRO





Block/ Object





How the 5200 Compares to Hard Drives

1 Micron SSD outperforms an entire rack of 24 HDDs for a lower TCO







Which Model is Right for You?

How much endurance do you need?	5200 ECO read-intensive <1 DWPD	5200 PRO read-intensive <2 DWPD	5100 MAX mixed-use 5 DWPD
How much random write performance & consistency do you need?	✓	~	~~~
	Microsoft SQL (BI/DSS)		
		Microsoft SQL, Oracle Database, MySQL (oLTP)	
Which applications and	Ceph (media streaming: large object)	Ceph (small random block)	
workloads are you running?	Hadoop (HDFS primary storage)	Hadoop (accelerate HDD clusters)	
	NoSQL databases: Cassar (session activity, user track		
	VMWare vSAN (VDI, virtual		
How much capacity do you need?	Micron [®] Flex Capacity →	you have by converting higher capacity write performance and endurance	
	480GB - 7.68TB	960GB - 1.92TB	240GB - 1.92TB



For Workloads That Must Work Loads

MICRON® 9200 SERIES OF NVME™ SSDS

Why Micron for NVMe?



Performance that simply outclasses the competition

- Maximizes application throughput into business advantage
- Minimizes latencies for faster access to data and scalability



The right capacity for your demanding workload

- Actively tune capacity to optimize drive performance and endurance with Micron's FlexPro™
- High capacity to meet your needs—up to 11 TBs



Micron technology advantage

 Micron is 75% of your server value making your workloads faster, greener and revolutionary







A Closer Look at the Micron® 9200 Feature Details

Enterprise SSD	9200 MAX					9200 PRO						9200 ECO				
Form Factor	Factor U.2		HHHL			U.2			HHHL			U.2		HHHL		
Capacity	1.6TB	3.2TB	6.4TB	1.6TB	3.2TB	6.4TB	1.92TB	3.84TB	7.68TB	1.92TB	3.84TB	7.68TB	8TB	11TB	8TB	11TB
Interface	Gen 3 x4 NVMe		Gen 3 x8 NVMe			Gen 3 x4 NVMe			Gen 3 x8 NVMe			Gen 3 x4 NVMe		Gen 3 x8 NVMe		
Sequential Read/Write (GB/s) ¹	2.7/ 2.1	3.35/ 2.4	3.35/ 2.4	2.7/ 2.1	4.35/ 2.4	4.6/ 3.8	2.7/ 2.1	3.35/ 2.4	3.35/ 2.4	2.7/ 2.1	4.35/ 2.4	4.6/ 3.8	3.35/ 2.4	3.35/ 2.4	4.6/ 3.8	4.6/ 3.8
Random R/W (K IOPS) ²	620/ 270	800/ 255	800/ 260	620/ 270	1000/ 255	1000/ 260	620/ 170	800/ 130	800/ 135	620/ 170	1000/ 130	1000/ 135	800/ 110	800/ 95	1000/ 110	1000/ 95
Endurance (TBW, PB)	8.6	17.1	34.7	8.6	17.1	34.7	3.5	6.8	13.7	3.5	6.8	13.7	11.4	15.7	11.4	15.7
Typical Workload	Write					Mixed Use				Read						
NAND							Micron 3D TLC NAND									
MTTF (Million Device Hours)	7															
Advanced	Storag	ge Executi	ve SSD M	anagement, Enterprise	Data Path F	Protection,	Power Lo	ss Protect	ion, XPEF	RT Feature	s, High P	erformanc	e, Low Lat	ency, NVN	/I Express	Industry

Standard

Features



^{1.} Sequential Read/Write @128KB

^{2.} Random Read/Write @ 4KB

9200 Series Solid State Storage

- Excellent performance for demanding workloads
- Large capacities meet your increasing storage needs
- Multiple models for flexible solutions





	Read (Centric	Unknown Re	ead Centric	Mixed Use			
	Micron 9200 ECO	Intel P4500	Micron 9200 PRO	Intel	Micron 9200 MAX	Intel P4600		
Interface	NVMe PCle Gen3 x8	NVMe PCle Gen3 x4	NVMe PCle Gen3 x8		NVMe PCle Gen3 x8	NVMe PCle Gen3 x4		
Form Factor	HHHL, U.2 15mm	HHHL, U.2 15mm	HHHL, U.2 15mm		HHHL, U.2 15mm	HHHL, U.2 15mm		
Capacity ¹	8000-11000GB	1000-4000GB	1920-7680GB		1600-6400GB	1600-4000GB		
Encryption	None	SED	None		None	SED		
Endurance ²	0.8 DWPD	0.7 DWPD	1 DWPD		3 DWPD	2.9 DWPD		
MTTF	2 Mhrs	2 Mhrs	2 Mhrs	No Direct	2 Mhrs	2 Mhrs		
Warranty	5 Years	5 Years	5 Years	Comparison	5 Years	5 Years		
Random Read ³	900K IOPS	710K IOPS	900K IOPS		900K IOPS	703K IOPS		
Random Write ³	125K IOPS	68K IOPS	175K IOPS		275K IOPS	257K IOPS		
Sequential Read ³	5500 MB/s	3290 MB/s	5500 MB/s		5500 MB/s	3280 MB/s		
Sequential Write ³	3500 MB/s	1890 MB/s	3200 MB/s		3200 MB/s	2100 MB/s		
Active Power ⁴	30W	18.3W	30W		30W	20.7W		

^{† -} Specs based on publicly available information.

^{1 -} May not be available in all form factors

^{2 –} DWPD for a given capacity may vary slightly

^{3 -} Steady-state performance, may vary based on capacity

^{4 -} Highest average write power draw in family



Key Takeaways

- Demand is set for Exponential Growth for the foreseeable future.
- Market is in considerable supply constraint.
- We have the product portfolio you need to succeed.
- We own our own supply chain.
- We have the collateral to support you.
- We are committed to your business.





Thank You



